NSN 5962-01-120-4843

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Maximum Power Dissipation Rating:	
794.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Electrostatic sensitive and hermetically sealed and monolithic and schottky and burn in and bipolar	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Memory Device Type:	
Prom	
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	